Bipolar Power Transistors 40 V, 3.0 A, Low V_{CE(sat)} PNP Transistor

ON Semiconductor's e^2 PowerEdge family of low $V_{CE(sat)}$ transistors are surface mount devices featuring ultra low saturation voltage ($V_{CE(sat)}$) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC–DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

Features

- Complement to NSS40301MZ4 Series
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	40	Vdc
Collector-Base Voltage	V _{CB}	40	Vdc
Emitter-Base Voltage	V _{EB}	6.0	Vdc
Base Current – Continuous	Ι _Β	1.0	Adc
Collector Current – Continuous	Ι _C	3.0	Adc
Collector Current – Peak	I _{CM}	5.0	Adc
Total Power Dissipation Total P _D @ T _A = 25°C (Note 1) Total P _D @ T _A = 25°C (Note 2)	P _D	2.0 0.80	W
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

MAXIMUM RATINGS ($T_C = 25^{\circ}C$ unless otherwise noted)

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Mounted on 1" sq. (645 sq. mm) Collector pad on FR-4 bd material.

2. Mounted on 0.012" sq. (7.6 sq. mm) Collector pad on FR-4 bd material.



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PNP TRANSISTOR 3.0 AMPERES 40 VOLTS, 2.0 WATTS





- W = Work Week 40300 = Specific Devic
 - 0300 = Specific Device Code
 - = Pb-Free Package

PIN ASSIGNMENT



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case Junction-to-Ambient on 1" sq. (645 sq. mm) Collector pad on FR-4 bd material Junction-to-Ambient on 0.012" sq. (7.6 sq. mm) Collector pad on FR-4 bd material	R _{θJA} R _{θJA}	64 155	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	260	°C

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Мах	Unit	
OFF CHARACTERISTICS						
Collector–Emitter Sustaining Voltage ($I_C = 10 \text{ mAdc}, I_B = 0 \text{ Adc}$)	V _{CEO(sus)}	40	-	-	Vdc	
Emitter–Base Voltage ($I_E = 50 \ \mu Adc$, $I_C = 0 \ Adc$)	V _{EBO}	6.0	-	-	Vdc	
Collector Cutoff Current (V _{CB} = 40 Vdc)	I _{CBO}	-	-	100	nAdc	
Emitter Cutoff Current (V _{BE} = 6.0 Vdc)	I _{EBO}	-	_	100	nAdc	

ON CHARACTERISTICS (Note 3)

	V _{CE(sat)}	- - -	- - -	0.070 0.150 0.400	Vdc
Base–Emitter Saturation Voltage ($I_C = 1.0 \text{ Adc}, I_B = 0.1 \text{ Adc}$)	V _{BE(sat)}	-	-	1.0	Vdc
Base-Emitter On Voltage (I_C = 1.0 Adc, V_{CE} = 2.0 Vdc)	V _{BE(on)}	-	-	0.9	Vdc
$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = 0.5 \; \text{Adc}, V_{CE} = 1.0 \; \text{Vdc}) \\ (I_{C} = 1.0 \; \text{Adc}, V_{CE} = 1.0 \; \text{Vdc}) \\ (I_{C} = 3.0 \; \text{Adc}, V_{CE} = 1.0 \; \text{Vdc}) \end{array} $	h _{FE}	200 175 100		_ 350 _	-

DYNAMIC CHARACTERISTICS

Output Capacitance (V _{CB} = 10 Vdc, f = 1.0 MHz)	C _{ob}	-	40	-	pF
Input Capacitance (V _{EB} = 5.0 Vdc, f = 1.0 MHz)	C _{ib}	-	130	-	pF
Current–Gain – Bandwidth Product (Note 4) $(I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}, F_{test} = 1.0 \text{ MHz})$	f _T	_	160	-	MHz

3. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%. 4. f_T = |h_{FE}| • f_{test}



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



ORDERING INFORMATION

Device	Package	Shipping [†]
NSS40300MZ4T1G	SOT-223 (Pb-Free)	1,000 / Tape & Reel
NSV40300MZ4T1G*	SOT-223 (Pb-Free)	1,000 / Tape & Reel
NSS40300MZ4T3G	SOT-223 (Pb-Free)	4,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

Capable

PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04

ISSUE N



NOTES:

STYLE 1: PIN 1. BASE

2. COLLECTOR 3. EMITTER 4. COLLECTOR

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
CONTROLLING DIMENSION: INCH.

	м	ILLIMETE	RS	INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
с	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
Е	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	_	10°



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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